Rochester Electronics

Datasheet

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)

    - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

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SN74LS640, SN74LS641, SN74LS642, SN74LS645

Octal Bus Transceivers

These octal bus transceivers are designed for asynchronous two-way communication between data buses. Control function implementation minimizes external timing requirements. These circuits allow data transmission from the A bus to B or from the B bus to A bus depending upon the logic level of the direction control (DIR) input. Enable input ($\overline{G}$) can disable the device so that the buses are effectively isolated.

DEVICE	OUTPUT	LOGIC
LS640	3-State	Inverting
LS641	Open-Collector	True
LS642	Open-Collector	Inverting
LS645	3-State	True

FUNCTION TABLE

CONTROL INPUTS		OPERATION	
		LS640 LS642	LS641 LS645
$\overline{G}$	DIR		
L	L	$\overline{B}$ data to A bus	B data to A bus
L	H	$\overline{A}$ data to B bus	A data to B bus
H	X	Isolation	Isolation

H = HIGH Level, L = LOW Level, X = Irrelevant

GUARANTEED OPERATING RANGES (SN74LS640, SN74LS645)

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	4.75	5.0	5.25	V
T_A	Operating Ambient Temperature Range	0	25	70	°C
I_{OH}	Output Current – High			–3.0	mA
				–15	mA
I_{OL}	Output Current – Low			24	mA

GUARANTEED OPERATING RANGES (SN74LS641, SN74LS642)

Symbol	Parameter	Min	Typ	Max	Unit
V_{CC}	Supply Voltage	4.75	5.0	5.25	V
T_A	Operating Ambient Temperature Range	0	25	70	°C
V_{OH}	Output Voltage – High			5.5	V
I_{OL}	Output Current – Low			24	mA

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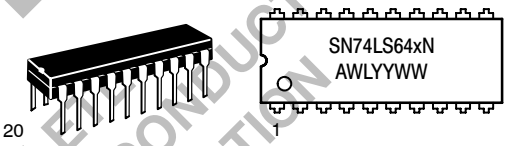
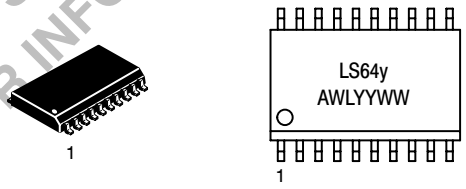
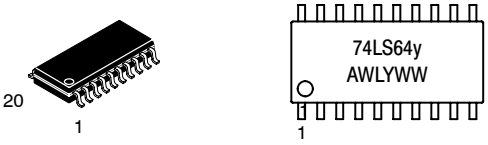
MARKING DIAGRAMS



PDIP–20
N SUFFIX
CASE 738



SOIC–20
DW SUFFIX
CASE 751D



SOEIAJ–20
M SUFFIX
CASE 967

x = 0, 1, 2, or 5
y = 0, 1, or 2
A = Assembly Location
WL = Wafer Lot
Y, YY = Year
WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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CONNECTION DIAGRAMS DIP (TOP VIEW)

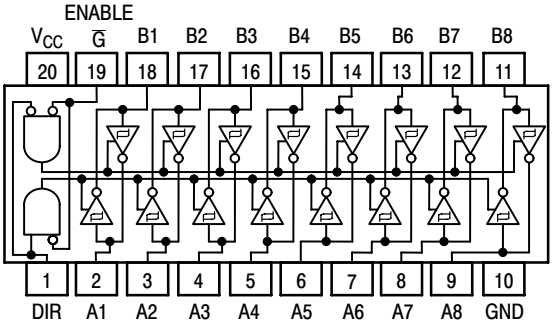

Figure 1. SN74LS640
SN74LS642

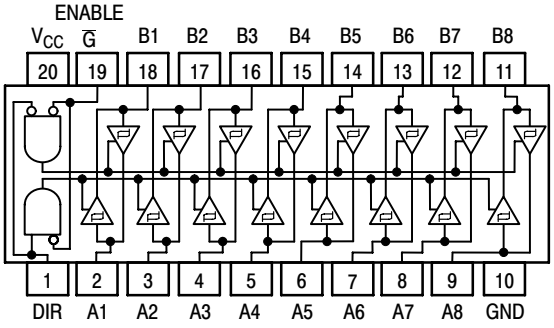

Figure 2. SN74LS641
SN74LS645

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SN74LS640 • SN74LS645

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter		Limits Min	Typ	Max	Unit	Test Conditions	
V_{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V_{IL}	Input LOW Voltage				0.6	V	Guaranteed Input LOW Voltage for All Inputs	
V_{IK}	Input Clamp Diode Voltage			−0.65	−1.5	V	V_{CC} = MIN, I_{IN} = −18 mA	
V_{OH}	Output HIGH Voltage		2.4	3.4		V	V_{CC} = MIN, I_{OH} = 3.0 mA	
			2.0			V	V_{CC} = MIN, I_{OH} = MAX	
V_{OL}	Output LOW Voltage			0.25	0.4	V	I_{OL} = 12 mA	V_{CC} = V_{CC} MIN, V_{IN} = V_{IL} or V_{IH} per Truth Table
				0.35	0.5	V	I_{OL} = 24 mA	
I_{OZH}	Output Off Current HIGH				20	μA	V_{CC} = MAX, V_{OUT} = 2.7 V	
I_{OZL}	Output Off Current LOW				−400	μA	V_{CC} = MAX, V_{OUT} = 0.4 V	
I_{IH}	Input HIGH Current	A or B, DIR or $\overline{G}$			20	μA	V_{CC} = MAX, V_{IN} = 2.7 V	
		DIR or $\overline{G}$			0.1	mA	V_{CC} = MAX, V_{IN} = 7.0 V	
		A or B			0.1	mA	V_{CC} = MAX, V_{IN} = 5.5 V	
I_{IL}	Input LOW Current				−0.4	mA	V_{CC} = MAX, V_{IN} = 0.4 V	
I_{OS}	Output Short Circuit Current (Note 1)		−40		−225	mA	V_{CC} = MAX	
I_{CC}	Power Supply Current Total Output HIGH				70	mA	V_{CC} = MAX	
	Total, Output LOW				90			
	Total at HIGH Z				95			

1. Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

Symbol	Parameter	Limits LS640 Min	LS640 Typ	LS640 Max	LS645 Min	LS645 Typ	LS645 Max	Unit	Test Conditions
t_{PLH} t_{PHL}	Propagation Delay A to B		6.0 8.0	10 15		8.0 11	15 15	ns	C_L = 45 pF, R_L = 667 Ω
t_{PLH} t_{PHL}	Propagation Delay B to A		6.0 8.0	10 15		8.0 11	15 15	ns	
t_{PZL} t_{PZH}	Output Enable Time $\overline{G}$, DIR to A		31 23	40 40		31 26	40 40	ns	
t_{PZL} t_{PZH}	Output Enable Time $\overline{G}$, DIR to B		31 23	40 40		31 26	40 40	ns	
t_{PLZ} t_{PHZ}	Output Disable Time $\overline{G}$, DIR to A		15 15	25 25		15 15	25 25	ns	C_L = 5.0 pF
t_{PLZ} t_{PHZ}	Output Disable Time $\overline{G}$, DIR to B		15 15	25 25		15 15	25 25	ns	

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DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter	Limits			Unit	Test Conditions	
		Min	Typ	Max			
V_{IH}	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs	
V_{IL}	Input LOW Voltage			0.6	V	Guaranteed Input LOW Voltage for All Inputs	
V_{IK}	Input Clamp Diode Voltage		−0.65	−1.5	V	V_{CC} = MIN, I_{IN} = −18 mA	
I_{OH}	Output HIGH Current			100	μA	V_{CC} = MIN, V_{OH} = MAX	
V_{OL}	Output LOW Voltage		0.25	0.4	V	I_{OL} = 12 mA	V_{CC} = V_{CC} MIN, V_{IN} = V_{IL} or V_{IH} per Truth Table
			0.35	0.5	V	I_{OL} = 24 mA	
I_{IH}	Input HIGH Current			20	μA	V_{CC} = MAX, V_{IN} = 2.7 V	
				−0.1	mA	V_{CC} = MAX, V_{IN} = 7.0 V	
I_{IL}	Input LOW Current			−0.4	mA	V_{CC} = MAX, V_{IN} = 0.4 V	
I_{CC}	Power Supply Current Total, Output HIGH			70	mA	V_{CC} = MAX	
	Total, Output LOW			90			
	Total at HIGH Z			95			

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V)

Symbol	Parameter	Limits						Unit	Test Conditions
		LS641			LS642				
		Min	Typ	Max	Min	Typ	Max		
t_{PLH} t_{PHL}	Propagation Delay, A to B		17 16	25 25		19 14	25 25	ns	C_L = 45 pF, R_L = 667 Ω
t_{PLH} t_{PHL}	Propagation Delay, B to A		17 16	25 25		19 14	25 25	ns	
t_{PLH} t_{PHL}	Propagation Delay, $\overline{G}$, DIR to A		23 34	40 50		26 43	40 60	ns	
t_{PLH} t_{PHL}	Propagation Delay, $\overline{G}$, DIR to B		25 37	40 50		28 39	40 60	ns	

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DEVICE ORDERING INFORMATION

Device Order Number	Package Type	Tape and Reel Size
SN74LS640N	PDIP−20	1440 Units/Box
SN74LS640DW	SOIC−WIDE	2500/Tape and Reel
SN74LS640DWR2	SOIC−WIDE	2500/Tape and Reel
SN74LS640M	SOEIAJ−20	See Note 2
SN74LS640MEL	SOEIAJ−20	See Note 2
SN74LS641N	PDIP−20	1440 Units/Box
SN74LS641DW	SOIC−WIDE	2500/Tape and Reel
SN74LS641DWR2	SOIC−WIDE	2500/Tape and Reel
SN74LS641M	SOEIAJ−20	See Note 2
SN74LS641MEL	SOEIAJ−20	See Note 2
SN74LS642N	PDIP−20	1440 Units/Box
SN74LS642DW	SOIC−WIDE	2500/Tape and Reel
SN74LS642DWR2	SOIC−WIDE	2500/Tape and Reel
SN74LS642M	SOEIAJ−20	See Note 2
SN74LS642MEL	SOEIAJ−20	See Note 2
SN74LS645N	PDIP−20	1440 Units/Box

2. For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

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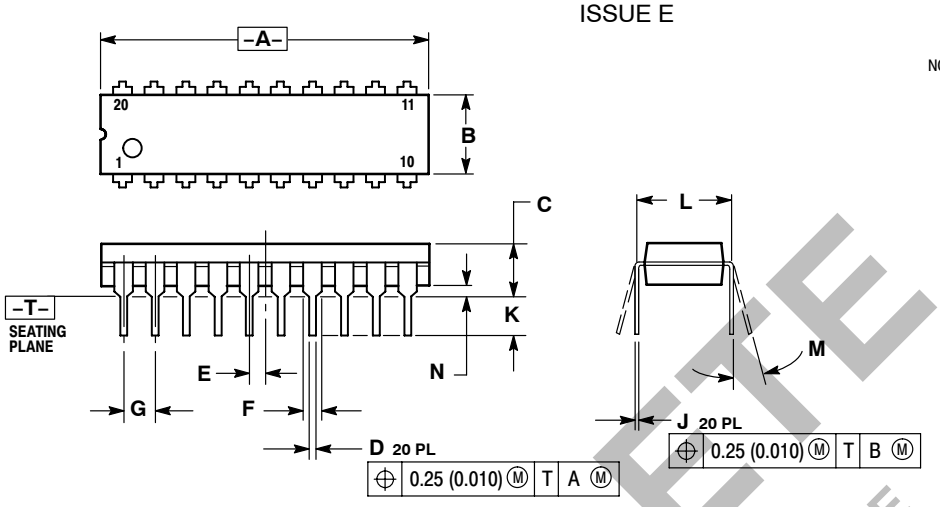
PACKAGE DIMENSIONS

N SUFFIX
PLASTIC PACKAGE
CASE 738−03
ISSUE E



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	1.010	1.070	25.66	27.17
B	0.240	0.260	6.10	6.60
C	0.150	0.180	3.81	4.57
D	0.015	0.022	0.39	0.55
E	0.050 BSC		1.27 BSC	
F	0.050	0.070	1.27	1.77
G	0.100 BSC		2.54 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.140	2.80	3.55
L	0.300 BSC		7.62 BSC	
M	0°	15°	0°	15°
N	0.020	0.040	0.51	1.01

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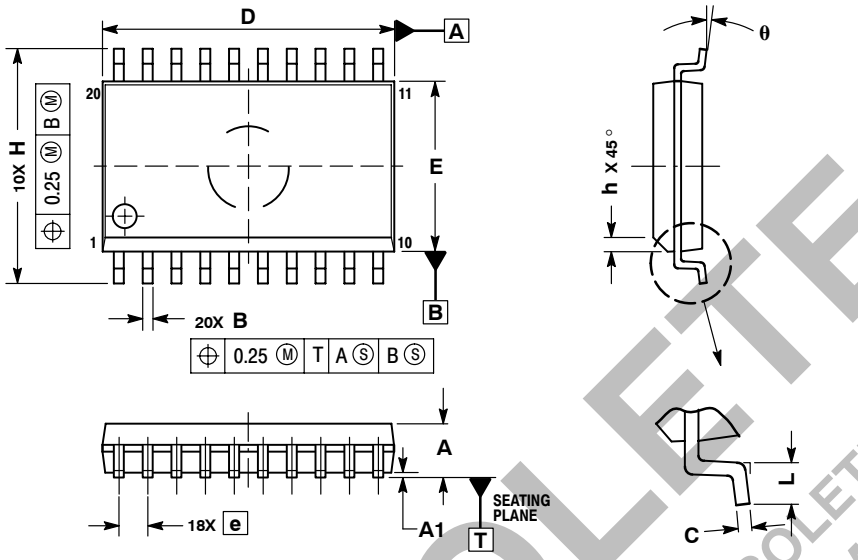
PACKAGE DIMENSIONS

D SUFFIX
PLASTIC SOIC PACKAGE
CASE 751D–05
ISSUE F



NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS	
DIM	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

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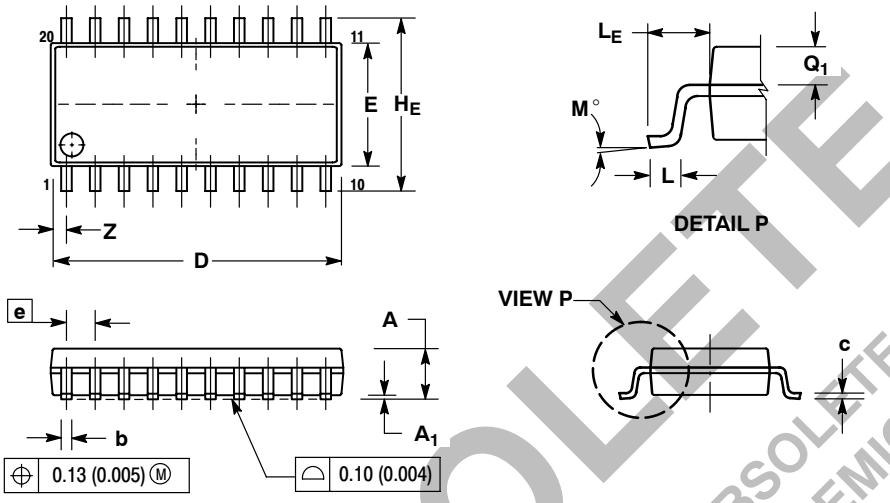
PACKAGE DIMENSIONS

M SUFFIX
SOEIAJ PACKAGE
CASE 967–01
ISSUE O



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A_1	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	12.35	12.80	0.486	0.504
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
H_E	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
L_E	1.10	1.50	0.043	0.059
M	0 °	10 °	0 °	10 °
Q_1	0.70	0.90	0.028	0.035
Z	---	0.81	---	0.032

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